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	Filing Date		2006-09-28	
	First Named Inventor	Rolf Kaufmann		
	Art Unit	2815		
	Examiner Name	EFTEKHARZADEH, ARDESHIR		
	Attorney Docket Number	0154.0354US1		

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1	GATTI, E. et al., "Semiconductor Drift Chamber - An Application of a Novel Charge Transport Scheme," Nuclear Instruments and Methods in Physics Research, Vol. 225, pp. 608-614, 1984.	<input type="checkbox"/>
2	GATTI, E. et al., "Silicon Drift Chambers - First Results and Optimum Processing of Signals," Nuclear Instruments and Methods in Physics Research, Vol. 226, pp. 129-141, 1984.	<input type="checkbox"/>
3	KEMMER, J. et al., "New Detector Concepts," Nuclear Instruments and Methods in Physics Research, Vol. A253, pp. 365-377, 1987.	<input type="checkbox"/>
4	SEITZ, P. et al., "Smart optical and image sensors fabricated with industrial CMOS/CCD semiconductor processes," Proc. SPIE Vol. 1900, p. 21-30, Charge-Coupled Devices and Solid State Optical Sensors III, 2-3 February 1993.	<input type="checkbox"/>

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